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FORM PTO-1	INFORMATION DISCLOSURE CITATION									Docket Number (Applicati n N 08/851,946	lumb r			
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FORM PTO-1449 U.S. Department of Commerce (REV. 7-80) PATENT AND TRADEMARK OFFICE

INFORMATION DISCLOSURE STATEMENT

(Use several sheets if necessary)

Attorney Docket No. 1390.C1/PVD/DV	Serial No. 08/851,946	. PTO
Applicant(s) NULMAN, et al.		8 U.S /052
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1	АВ	5	1	7	5	6	0	8	12/29/92	Nihei et al.	257	751	
	AC	5	1	7	8_	7	3	9	1/12/93	Barnes et al.	204	192.12	
	AD	4	7	1	6	4	9	1	12/29/87	Ohno et al.	361	130	
	AE	4	9	1	8	0	3	1	4/17/90	Flamm et al.	438	695	
	AF	4	9	4	8	4	5	8	8/14/90	Ogle	4348	729	
	AG	5	3	4	6	5	7	8	9/13/94	Benzing et al.	156	345,48	
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	AJ	5	1_	3	5	6	2	9	8/92	Sawada et al.	204	192.12	
	AK	4	3	6	2	6	3	2	12/82	Jacob	422	186 04	
	AL	5	1	4	6	1	3	7	9/8/92	Gesche et al.	315	111.21	
	АМ	4	9	9	0	2	2	9	2/5/91	Campbell et al.	204	298.06	
	AN	4	8	4	4	7	7	5	7/4/89	Keeble	216	68	
	AO	5	4	3	0	3	5	5	7/4/95	Paranjpe	315	11/21	
	ΑP	5	4	2	9	9	9	5	7/4/95	Nishiyama et al.	438	788	
	AQ	5	4	2	9	7	1	0	7/4/95	Akiba et al.	438	714	
	AR	5	4	2	9	0	7	0	7/4/95	Campbell et al.	119	171	
	AS	5	4	2	1	8	9	1	6/6/95	Campbell et al.	118	723R	
	AT	5	4	1	8	4	3	1	5/23/95	Williamson et al.	315	111.51	· · · · · · · · · · · · · · · · · · ·
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	AW	5	3	6	6	5	9	0	11/22/94	Kadomura	438	723	
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		BA	5	2	3	1	3	3	4	7/27/93	Paranjpe	3/5	iosep (1000	11.2	
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		BE	5	0	9	1	0	4	9	2/25/92	Campbell	et al.	246	37		
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	!		OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)													
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	DB	M. Ya	Phys., vol. 26, pp. 721-727, 1987 M. Yamashita, "Fundamental Characteristics of Built-in High Frequency Coil Type Sputtering Apparatus," J. Vac. Sci. Technol., vol. A7, pp. 151-158, 1989													
	DC	Vac. Sci. Technol., vol. A7, pp. 151-158, 1989 S.M. Rossnagel et al., "Metal Ion Deposition from Ionized Magnetron Sputtering Discharge," J. Vac. Sci. Technol., vol. B12, pp. 449-453, 1994												Sci.		
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	DE		Lett., vol. 63, pp. 3285-3287, 1993 S.M. Rossnagel, et al., "Filling Dual Damascene Interconnect Structures with AlCu and Cu Using Ionized Magnetron Deposition," J. Vac. Sci. Technol., vol. B13, pp. 125-129, 1995													
	DF		Y-W. Kim et al., "Ionized Sputter Deposition of AlCu: Film Microstructure and Chemistry," <i>J. Vac. Sci. Technol.</i> , vol. A12, pp. 3169-3175, 1994													
	DG	J. Ho 765,			al., "N	/lecha	nism	s for	Highly Ionize	d Magnetro	n Sputtering,	" J. Appl.	Phys., vo	l. 78, pp	o.758-	
	DH								nd ECR Heat nol., vol. A9,			Coating a	nd Ion Sui	rface		
	DI	W.M. vol. A		-				eposit	ion by Electr	on Cyclotro	n Resonance	e Plasma	" J. Vac. S	Sci. Tec	hnol.,	
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FORM P'		9 U.S. Department of Commerce PATENT AND TRADEMARK OFFICE	Attorney Docket No. 1390.C1/PVD/DV	Serial No. 08/851,946								
	INF	ORMATION DISCLOSURE STATEMENT	Applicant(s) NULMAN, et al.									
	(Use several sheets if necessary) Filing Date Group 5/6/97											
DR U.S. patent application serial No. 07/954,860, filed 9/30/92 (Atty. Dk. 364)												
	DS	U.S. patent application serial No. 08/461,575, filed 9/30/92 (A	Atty. Dk. 364.F1)									
	DT	U.S. patent application serial No. 08/310,617, filed 9/30/92 (A	Atty. Dk. 364.P1)									
	DU	U.S. patent application serial No. 08/567,601, filed 6/2/95 (At	ty. Dk. 364.P2)									
	DV	U.S. patent application serial No. 08/647,182, filed 5/9/96 (At	ty. Dk. 1186)									
	DW U.S. patent application serial No. 08/559,345, filed November 15, 1995 (Aty. Dk. 938/PVD/DV)											
	DX	U.S. patent application serial No. 08/733,620, filed 10/17/96	(Attorney Docket # 14	57/PVD/DV)								
	DY	U.S. patent application serial No. 08/741,708, filed 10/31/96	(Attorney Docket # 15	90/PVD/DV)								
	DAA	U.S. patent application serial No. 08/846,335, filed 5/14/97 (A	Atty. Dk. 1736/PVD/D\	/)								
	DAB	U.S. patent application serial No. 08/853,024, filed 5/8/97 (At	ty. Dk. 1186.P1/PVD/	DV)								
	DAC	U.S. patent application serial No. 08/857,719, filed 5/16/97 (A	Atty. Dk. 1752/PVD/D\)								
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